**Design and layout of fully differential telescopic cascode amplifier with CMFB:**

* Designed differential telescopic opamp for the Gain = 72 dB, differential output swing = 3V, power dissipation = 10mW, Gain-Bandwidth product: 122MHz, supply = 3V.
* Obtained device dimensions form required output swing, bias current, overdrive voltages and increased PMOS devices width for higher gain.
* Obtained bias voltages from input CM level, Performed DC analysis to check the operating point of all the transistors, AC, stb analysis to find loop gain, stability requirements.
* Located poles of the opamp and increased output capacitance for meeting the bandwidth and phase margin requirements.

**Process corner analysis and Monte Carlo analysis:**

* Analyzed variation of βeff and Vth variation of four diode connected MOSFET’s under different process corners by setting the environment in ADEXL (Process-Mismatch statistical variation in Montecarlo).
* Understood process corners like strong, weak, typical and respective Vth and current variation by doing DC analysis on four transistors.

**Designed Bandgap reference circuit:**

* Designed CTAT circuit with a diode (BJT), PTAT with the series of diodes (BJT) and simulated respective voltages in reference to temperature.
* Observed PTAT slope is lesser than CTAT, used ratio of resistors to scale the PTAT with CTAT.
* Obtained reference voltage as 1.2 V and simulated the bandgap circuit in various process corners.
* Achieved low temperature coefficients of 150ppm/C across temperature range of -20oC to 120oC by efficient slope cancellation of PTAT and CTAT currents.